

# 8-Bit Buffered Multiplying DAC

AD7524

#### **FEATURES**

Microprocessor Compatible (6800, 8085, Z80, Etc.)
TTL/CMOS Compatible Inputs
On-Chip Data Latches
Endpoint Linearity
Low Power Consumption
Monotonicity Guaranteed (Full Temperature Range)
Latch Free (No Protection Schottky Required)

### **APPLICATIONS**

Microprocessor Controlled Gain Circuits Microprocessor Controlled Attenuator Circuits Microprocessor Controlled Function Generation Precision AGC Circuits Bus Structured Instruments

#### GENERAL DESCRIPTION

The AD7524 is a low cost, 8-bit monolithic CMOS DAC designed for direct interface to most microprocessors.

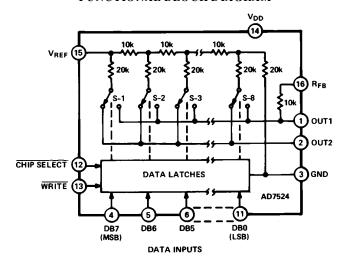
Basically an 8-bit DAC with input latches, the AD7524's load cycle is similar to the "write" cycle of a random access memory. Using an advanced thin-film on CMOS fabrication process, the AD7524 provides accuracy to 1/8 LSB with a typical power dissipation of less than 10 milliwatts.

A newly improved design eliminates the protection Schottky previously required and guarantees TTL compatibility when using a +5 V supply. Loading speed has been increased for compatibility with most microprocessors.

Featuring operation from +5 V to +15 V, the AD7524 interfaces directly to most microprocessor buses or output ports.

Excellent multiplying characteristics (2- or 4-quadrant) make the AD7524 an ideal choice for many microprocessor controlled gain setting and signal control applications.

### FUNCTIONAL BLOCK DIAGRAM



### **ORDERING GUIDE**

| Model <sup>1</sup> | Temperature<br>Range | Nonlinearity $(V_{DD} = +15 \text{ V})$ | Package<br>Option <sup>2</sup> |
|--------------------|----------------------|---|--------------------------------|
| AD7524JN           | -40°C to +85°C       | ±1/2 LSB                                | N-16                           |
| AD7524KN           | −40°C to +85°C       | ±1/4 LSB                                | N-16                           |
| AD7524LN           | −40°C to +85°C       | ±1/8 LSB                                | N-16                           |
| AD7524JP           | -40°C to +85°C       | ±1/2 LSB                                | P-20A                          |
| AD7524KP           | −40°C to +85°C       | ±1/4 LSB                                | P-20A                          |
| AD7524LP           | −40°C to +85°C       | ±1/8 LSB                                | P-20A                          |
| AD7524JR           | -40°C to +85°C       | ±1/2 LSB                                | R-16A                          |
| AD7524AQ           | −40°C to +85°C       | ±1/2 LSB                                | Q-16                           |
| AD7524BQ           | −40°C to +85°C       | ±1/4 LSB                                | Q-16                           |
| AD7524CQ           | -40°C to +85°C       | ±1/8 LSB                                | Q-16                           |
| AD7524SQ           | −55°C to +125°C      | ±1/2 LSB                                | Q-16                           |
| AD7524TQ           | −55°C to +125°C      | ±1/4 LSB                                | Q-16                           |
| AD7524UQ           | −55°C to +125°C      | ±1/8 LSB                                | Q-16                           |
| AD7524SE           | −55°C to +125°C      | ±1/2 LSB                                | E-20A                          |
| AD7524TE           | −55°C to +125°C      | ±1/4 LSB                                | E-20A                          |
| AD7524UE           | −55°C to +125°C      | ±1/8 LSB                                | E-20A                          |

#### NOTES

<sup>1</sup>To order MIL-STD-883, Class B processed parts, add/883B to part number. Contact your local sales office for military data sheet. For U.S. Standard Military Drawing (SMD) see DESC drawing #5962-87700.

 $^2$ E = Leadless Ceramic Chip Carrier: N = Plastic DIP; P = Plastic Leaded Chip Carrier; Q = Cerdip; R = SOIC.

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|   |                        |  |                       |   | I                                     |   |
|---|------------------------|--|-----------------------|---|---------------------------------------|---|
| Parameter                                     | Limit,                 | $T_{A} = +25^{\circ}C$ $ V_{DD} = +15 V$ | Limit,                | $\Gamma_{MIN}, T_{MAX}^{1}$ $\mid V_{DD} = +15 \text{ V}$ | Units                                 | Test Conditions/Comments  |
| -   | V <sub>DD</sub> = +5 V | V <sub>DD</sub> = +15 V                  | V <sub>DD</sub> = 3 V | V <sub>DD</sub> = +15 V                                   | Units                                 | Test Conditions/Comments  |
| STATIC PERFORMANCE                            |                        |  | 0                     |   | D:-                                   |   |
| Resolution                                    | 8                      | 8  | 8                     | 8   | Bits                                  |   |
| Relative Accuracy J, A, S Versions            | ±1/2                   | ±1/2                                     | ±1/2                  | ±1/2  | LSB max                               |   |
| K. B. T Versions                              | ±1/2                   | ±1/4                                     | ±1/2                  | ±1/4  | LSB max                               |   |
| L, C, U Versions                              | ±1/2                   | ±1/8                                     | ±1/2                  | ±1/8  | LSB max                               |   |
| Monotonicity                                  | Guaranteed             | Guaranteed                               | Guaranteed            | Guaranteed  | Los mun                               |   |
| Gain Error <sup>2</sup>                       | ±2 1/2                 | ±1 1/4                                   | ±3 1/2                | ±1 1/2  | LSB max                               |   |
| Average Gain TC <sup>3</sup>                  | ±40                    | ±10                                      | ±40                   | ±10   | ppm/°C                                | Gain TC Measured from +25°C to  |
|   |                        |  |                       |   |                                       | T <sub>MIN</sub> or from +25°C to T <sub>MAX</sub>  |
| DC Supply Rejection, 3 ΔGain/ΔV <sub>DD</sub> | 0.08                   | 0.02                                     | 0.16                  | 0.04  | % FSR/% max                           | $\Delta V_{DD} = \pm 10\%$  |
|   | 0.002                  | 0.001                                    | 0.01                  | 0.005   | % FSR/% typ                           |   |
| Output Leakage Current                        |                        |  |                       |   |                                       |   |
| I <sub>OUT1</sub> (Pin 1)                     | ±50                    | ±50                                      | ±400                  | ±200  | nA max                                | DB0-DB7 = 0 V; $\overline{WR}$ , $\overline{CS}$ = 0 V; $V_{REF}$ = ±10 V                       |
| I <sub>OUT2</sub> (Pin 2)                     | ±50                    | ±50                                      | ±400                  | ±200  | nA max                                | DB0-DB7 = $V_{DD}$ ; $\overline{WR}$ , $\overline{CS}$ = 0 V; $V_{REF}$ = ±10 V                 |
| DYNAMIC PERFORMANCE                           |                        |  |                       |   |                                       |   |
| Output Current Settling Time <sup>3</sup>     |                        |  |                       |   |                                       |   |
| (to 1/2 LSB)                                  | 400                    | 250                                      | 500                   | 350   | ns max                                | OUT 1 Load = $100 \Omega$ , $C_{EXT} = 13 pF$ ; $\overline{WR}$ , $\overline{CS} =$             |
| ,   |                        |  |                       |   |                                       | $0 \text{ V}; \text{DB0-DB7} = 0 \text{ V to V}_{\text{DD}} \text{ to 0 V}.$                    |
| AC Feedthrough <sup>3</sup>                   |                        |  |                       |   |                                       |   |
| at OUT 1                                      | 0.25                   | 0.25                                     | 0.5                   | 0.5   | % FSR max                             | $V_{REF} = \pm 10 \text{ V}$ , 100 kHz Sine Wave; DB0-DB7 =                                     |
| at OUT2                                       | 0.25                   | 0.25                                     | 0.5                   | 0.5   | % FSR max                             | $0 \text{ V}; \overline{\text{WR}}, \overline{\text{CS}} = 0 \text{ V}$                         |
| REFERENCE INPUT                               |                        |  |                       |   |                                       |   |
| $R_{IN}$ (Pin 15 to GND) <sup>4</sup>         | 5                      | 5  | 5                     | 5   | kΩ min                                |   |
|   | 20                     | 20                                       | 20                    | 20  | kΩ max                                |   |
| ANALOG OUTPUTS                                |                        | -  |                       |   |                                       |   |
| Output Capacitance <sup>3</sup>               |                        |  |                       |   |                                       |   |
| C <sub>OUT1</sub> (Pin 1)                     | 120                    | 120                                      | 120                   | 120   | pF max                                | $DB0-DB7 = V_{DD}; \overline{WR}, \overline{CS} = 0 \text{ V}$                                  |
| $C_{OUT2}$ (Pin 2)                            | 30                     | 30                                       | 30                    | 30  | pF max                                | DB0-DB7 = V <sub>DD</sub> , wik, CS = 0 V   |
| C <sub>OUT1</sub> (Pin 1)                     | 30                     | 30                                       | 30                    | 30  | pF max                                | $DB0-DB7 = 0 \text{ V}; \overline{WR}, \overline{CS} = 0 \text{ V}$                             |
| C <sub>OUT2</sub> (Pin 2)                     | 120                    | 120                                      | 120                   | 120   | pF max                                | DB0 BB7 = 0 1, WIG G0 = 0 1   |
| DIGITAL INPUTS                                | 1                      |  |                       |   | r                                     |   |
| Input HIGH Voltage Requirement                |                        |  |                       |   |                                       |   |
| V <sub>IH</sub>                               | +2.4                   | +13.5                                    | +2.4                  | +13.5   | V min                                 |   |
| Input LOW Voltage Requirement                 | 72.4                   | 13.3                                     | 72.4                  | +13.3   | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |   |
| V <sub>IL</sub>                               | +0.8                   | +1.5                                     | +0.5                  | +1.5  | V max                                 |   |
| Input Current                                 | 1 0.0                  |  | . 0.5                 |   | ,                                     |   |
| I <sub>IN</sub>                               | ±1                     | ±1                                       | ±10                   | ±10   | μA max                                | $V_{IN} = 0 \text{ V or } V_{DD}$   |
| Input Capacitance <sup>3</sup>                |                        |  |                       |   | •                                     |   |
| DB0-DB7                                       | 5                      | 5  | 5                     | 5   | pF max                                | $V_{IN} = 0 V$  |
| $\overline{WR}$ , $\overline{CS}$             | 20                     | 20                                       | 20                    | 20  | pF max                                | $V_{IN} = 0 V$  |
| SWITCHING CHARACTERISTICS                     |                        |  |                       |   |                                       |   |
| Chip Select to Write Setup Time <sup>5</sup>  |                        |  |                       |   |                                       | See Timing Diagram  |
| $t_{CS}$                                      |                        |  |                       |   |                                       | $t_{WR} = t_{CS}$   |
| AD7524J, K, L, A, B, C                        | 170                    | 100                                      | 220                   | 130   | ns min                                |   |
| AD7524S, T, U                                 | 170                    | 100                                      | 240                   | 150   | ns min                                |   |
| Chip Select to Write Hold Time                |                        |  |                       |   |                                       |   |
| $t_{CH}$                                      |                        |  |                       |   |                                       |   |
| All Grades                                    | 0                      | 0  | 0                     | 0   | ns min                                |   |
| Write Pulse Width                             |                        |  |                       |   |                                       |   |
| t <sub>WR</sub>                               | 170                    | 100                                      | 220                   | 120   |                                       | $t_{\rm CS} \ge t_{\rm WR}, t_{\rm CH} \ge 0$   |
| AD7524S, K, L, A, B, C                        | 170                    | 100                                      | 220                   | 130   | ns min                                |   |
| AD7524S, T, U                                 | 170                    | 100                                      | 240                   | 150   | ns min                                |   |
| Data Setup Time                               |                        |  |                       |   |                                       |   |
| t <sub>DS</sub>                               | 135                    | 60                                       | 170                   | 80  | ne min                                |   |
| AD7524J, K, L, A, B, C<br>AD7524S, T, U       | 135                    | 60                                       | 170<br>170            | 100   | ns min<br>ns min                      |   |
| Data Hold Time                                | 133                    | 00                                       | 170                   | 100   | 118 111111                            |   |
| t <sub>DH</sub>                               |                        |  |                       |   |                                       |   |
| All Grades                                    | 10                     | 10                                       | 10                    | 10  | ns min                                |   |
|   | 1.0                    |  |                       |   |                                       |   |
| POWER SUPPLY                                  | 1                      | 2  | 2                     | 2   | m A mer                               | All Digital Inputs V <sub>II.</sub> or V <sub>IH</sub>  |
| $I_{ m DD}$                                   | 1 100                  | 100                                      | 500                   | 500   | mA max<br>µA max                      | All Digital Inputs V <sub>IL</sub> or V <sub>IH</sub> All Digital Inputs 0 V or V <sub>DD</sub> |
|   | 100                    | 100                                      | 200                   | 200   | μα ι iii α λ                          | 1 m 5 letter inhere o 4 or 4DD  |

# NOTES

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NOTES

1 Temperature ranges as follows: J, K, L versions: -40°C to +85°C

A, B, C versions: -40°C to +85°C

S, T, U versions: -55°C to +125°C

2 Gain error is measured using internal feedback resistor. Full-Scale Range (FSR) = V<sub>REF</sub>.

3 Guaranteed not tested.

4 DAC thin-film resistor temperature coefficient is approximately -300 ppm/°C.

5 AC parameter, sample tested @ +25°C to ensure conformance to specification.

Specifications subject to change without notice.

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### ABSOLUTE MAXIMUM RATINGS\*

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted})$ 

| $V_{DD}$ to GND                                      |
|--|
| $V_{RFB}$ to GND                                     |
| $V_{REF}$ to GND                                     |
| Digital Input Voltage to GND0.3 V to $V_{DD}$ +0.3 V |
| OUT1, OUT2 to GND0.3 V to $V_{DD}$ +0.3 V            |

\*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| Power Dissipation (Any Package)       |  |
|---------------------------------------|--|
| To +75°C                              | $\dots \dots $ |
| Derates above 75°C by                 | $\dots \dots \dots \ 6\ mW/^{\circ}C$  |
| Operating Temperature                 |  |
| Commercial (J, K, L)                  | $-40^{\circ}$ C to $+85^{\circ}$ C   |
| Industrial (A, B, C)                  | $\dots$ -40°C to +85°C   |
| Extended (S, T, U)                    | $-55$ °C to $+125$ °C  |
| Storage Temperature                   | $-65$ °C to $+150$ °C  |
| Lead Temperature (Soldering, 10 secs) | +300°C   |

### CAUTION \_

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD7524 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



### **TERMINOLOGY**

**RELATIVE ACCURACY:** A measure of the deviation from a straight line through the end points of the DAC transfer function. Normally expressed as a percentage of full scale range. For the AD7524 DAC, this holds true over the entire  $V_{\text{REF}}$  range.

**RESOLUTION:** Value of the LSB. For example, a unipolar converter with n bits has a resolution of  $(2^{-n})$  ( $V_{REF}$ ). A bipolar converter of n bits has a resolution of  $[2^{-(n-1)}]$  [ $V_{REF}$ ]. Resolution in no way implies linearity.

**GAIN ERROR:** Gain Error is a measure of the output error between an ideal DAC and the actual device output. It is measured

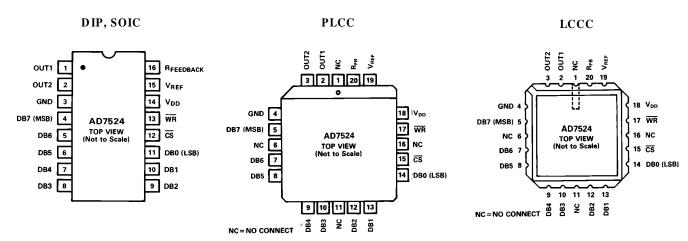
with all 1s in the DAC after offset error has been adjusted out and is expressed in LSBs. Gain Error is adjustable to zero with an external potentiometer.

**FEEDTHROUGH ERROR:** Error caused by capacitive coupling from  $V_{REF}$  to output with all switches OFF.

**OUTPUT CAPACITANCE:** Capacity from OUT1 and OUT2 terminals to ground.

**OUTPUT LEAKAGE CURRENT:** Current which appears on OUT1 terminal with all digital inputs LOW or on OUT2 terminal when all inputs are HIGH. This is an error current which contributes an offset voltage at the amplifier output.

# PIN CONFIGURATIONS



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# AD7524

# CIRCUIT DESCRIPTION CIRCUIT INFORMATION

The AD7524, an 8-bit multiplying D/A converter, consists of a highly stable thin film R-2R ladder and eight N-channel current switches on a monolithic chip. Most applications require the addition of only an output operational amplifier and a voltage or current reference.

The simplified D/A circuit is shown in Figure 1. An inverted R-2R ladder structure is used—that is, the binarily weighted currents are switched between the OUT1 and OUT2 bus lines, thus maintaining a constant current in each ladder leg independent of the switch state.

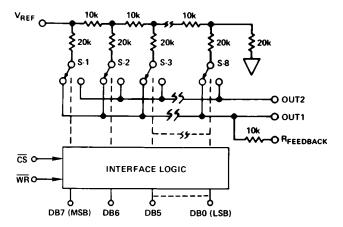


Figure 1. Functional Diagram

### **EQUIVALENT CIRCUIT ANALYSIS**

The equivalent circuit for all digital inputs LOW is shown in Figures 2. In Figure 2 with all digital inputs LOW, the reference current is switched to OUT2. The current source ILEAKAGE is composed of surface and junction leakages to the substrate

while the  $\frac{1}{256}$  current source represents a constant 1-bit cur-

rent drain through the termination resistor on the R-2R ladder. The "ON" capacitance of the output N-channel switches is 120 pF, as shown on the OUT2 terminal. The "OFF" switch capacitance is 30 pF, as shown on the OUT1 terminal. Analysis of the circuit for all digital inputs high is similar to Figure 2 however, the "ON" switches are now on terminal OUT 1, hence the 120 pF appears at that terminal.

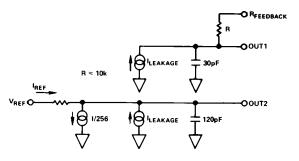


Figure 2. AD7524 DAC Equivalent Circuit—All Digital Inputs Low

# INTERFACE LOGIC INFORMATION MODE SELECTION

AD 7524 mode selection is controlled by the  $\overline{CS}$  and  $\overline{WR}$  inputs.

### WRITE MODE

When  $\overline{CS}$  and  $\overline{WR}$  are both LOW, the AD7524 is in the WRITE mode, and the AD7524 analog output responds to data activity at the DB0-DB7 data bus inputs. In this mode, the AD7524 acts like a nonlatched input D/A converter.

# HOLD MODE

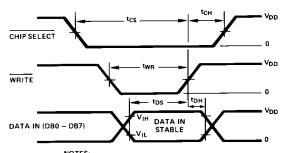
When either  $\overline{CS}$  or  $\overline{WR}$  is HIGH, the AD7524 is in the HOLD mode. The AD7524 analog output holds the value corresponding to the last digital input present at DB0-DB7 prior to WR or **CS** assuming the HIGH state.

### MODE SELECTION TABLE

| <del>CS</del> | WR | Mode  | DAC Response  |
|---------------|----|-------|---|
| L             | L  | Write | DAC responds to data bus (DB0-DB7) inputs.                    |
| Н             | X  | Hold  | Data bus (DB0-DB7) is<br>Locked Out:                          |
| X             | Н  | Hold  | DAC holds last data present when WR or CS assumed HIGH state. |

L = Low State, H = High State, X = Don't Care.

## WRITE CYCLE TIMING DIAGRAM



NOTES: 1. All input signal rise and fall times 10% to 90% of  $V_{DD}$ .  $V_{DD}$  = +5V,  $V_{DD}$  = +15V,  $t_r$  =  $t_f$  = 40ns.

2. Timing Measurement Reference le

3.  $t_{DS}$  +  $t_{DH}$  is approximately constant at 145ns min at +25°C,  $V_{DD}$  = +5V and  $t_{wr}$  = 170ns min. The AD7524 is specified for a minimum  $t_{DH}$  of 10ns, however, in applications where  $t_{DH}$  > 10ns,  $t_{DS}$  may be reduced accordingly up to the limit  $t_{DS}$  = 65ns,  $t_{DH}$  = 80ns.

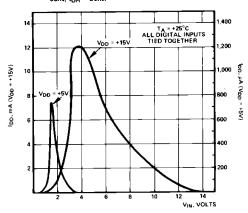


Figure 3. Supply Current vs. Logic Level Typical plots of supply current, I<sub>DD</sub>, versus logic input voltage,  $V_{IN}$ , for  $V_{DD} = +5$  V and  $V_{DD} = +15$  V are shown above.

## ANALOG CIRCUIT CONNECTIONS

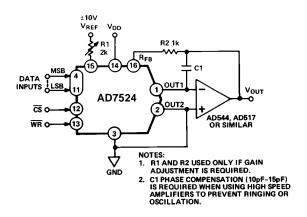


Figure 4. Unipolar Binary Operation (2-Quadrant Multiplication)

Table I. Unipolar Binary Code Table

| Digital Input<br>MSB LSB | Analog Output                        |
|--------------------------|--------------------------------------|
| 1111 1111                | -V <sub>REF</sub> (255/256)          |
| 1000 0001                | $-V_{REF}$ (129/256)                 |
| 1000 0000                | $-V_{REF}$ (128/256) = $-V_{REF}$ /2 |
| 0111 1111                | -V <sub>REF</sub> (127/256)          |
| 0000 0001                | $-V_{REF}$ (1/256)                   |
| 0000 0000                | $-V_{REF}(0/256) = 0$                |

Note:  $1 \text{ LSB} = (2^{-8})(V_{REF}) = 1/256 (V_{REF})$ 

# MICROPROCESSOR INTERFACE

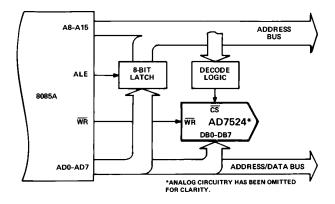


Figure 6. AD7524/8085A Interface

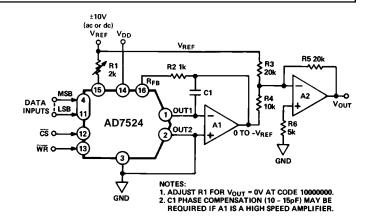


Figure 5. Bipolar (4-Quadrant) Operation

Table II. Bipolar (Offset Binary) Code Table

| Digital Input<br>MSB LSB | Analog Output               |
|--------------------------|-----------------------------|
| 1111 1111                | +V <sub>REF</sub> (127/128) |
| 1000 0001                | $+V_{REF}(1/128)$           |
| 1000 0000                | 0                           |
| 0111 1111                | $-V_{REF}$ (1/128)          |
| 0000 0001                | $-V_{REF}$ (127/128)        |
| 0000 0000                | $-V_{REF}$ (128/128)        |

Note: 1 LSB =  $(2^{-7})(V_{REF}) = 1/128 (V_{REF})$ 

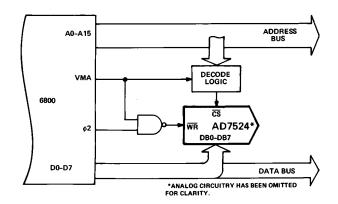


Figure 7. AD7524/MC6800 Interface

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# POWER GENERATION

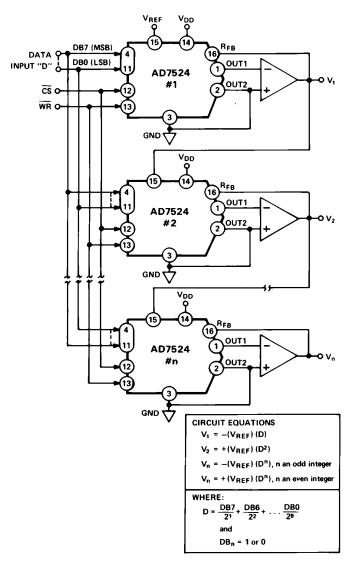


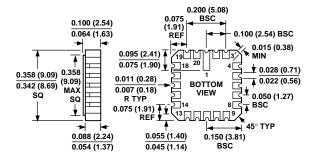
Figure 8.

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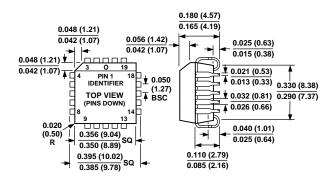
### **OUTLINE DIMENSIONS**

Dimensions shown in inches and (mm).

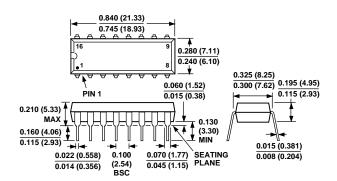
# 20-Terminal Ceramic Leadless Chip Carrier (E-20A)



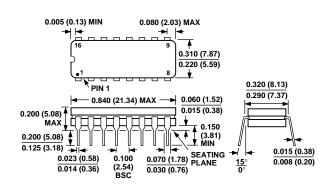
# 20-Lead Plastic Leadless Chip Carrier (PLCC) (P-20A)



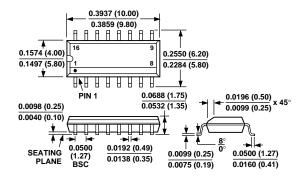
16-Lead Plastic DIP (Narrow) (N-16)



16-Lead Cerdip (Q-16)



16-Lead Narrow-Body (SOIC) (R-16A)



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